

Small Signal Schottky Diodes

Features

- · For surface mounted applications
- · Low-profile package
- Ideal for automated placement
- · Low power loss, high efficiency
- High temperature soldering: 260 °C/10 seconds at terminals
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



17249

Mechanical Data

Case: JEDEC DO-219AB (SMF) Plastic case Polarity: Color band denotes cathode end

Weight: approx. 15 mg Packaging codes-options:

G18 / 10 k per 13" reel (8 mm tape), 50 k/box G08 / 3 k per 7" reel (8 mm tape), 30 k/box

Parts Table

Part	Part Ordering code		Remarks	
SL02	SL02-GS18 or SL02-GS08	S2	Tape and Reel	
SL03	SL03-GS18 or SL03-GS08	S3	Tape and Reel	
SL04	SL04-GS18 or SL04-GS08	S4	Tape and Reel	

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit
Maximum repetitive peak reverse voltage		SL02	V _{RRM}	20	V
		SL03	V _{RRM}	30	V
		SL04	V _{RRM}	40	V
Maximum RMS voltage		SL02	V _{RMS}	14	V
		SL03	V _{RMS}	21	V
		SL04	V _{RMS}	28	V



Parameter	Test condition	Part	Symbol	Value	Unit
Maximum DC blocking voltage		SL02	V_{DC}	20	V
		SL03	V_{DC}	30	V
		SL04	V _{DC}	40	V
Maximum average forward rectified current	T _{tp} = 109 °C		I _{F(AV)}	1.1	А
Peak forward surge current 8.3 ms single half sine-wave			I _{FSM}	40	А

Thermal Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air ²⁾		R _{thJA}	180	K/W
Maximum operating junction temperature		T_J	125	°C
Storage temperature range		T _{STG}	- 55 to 150	°C

 $^{^{2)}\!}Mounted$ on epoxy substrate with 3 x 3 mm Cu pads (\geq 40 μm thick)

Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Instaneous forward voltage at		SL02	V _F		0.360	0.385	V
0.5 ¹⁾							
		SL03	V_{F}		0.395	0.43	V
		SL04	V_{F}		0.450	0.51	V
Typical instantaneous forward voltage	1.1 A	SL02	V _F		0.420		V
		SL03	V _F		0.450		V
		SL04	V_{F}		0.530		V
Maximum DC reverse current at rated DC blocking voltage	T _A = 25 °C	SL02	I _R			250	μА
	T _A = 100 °C	SL02	I _R			8.0	mA
	T _A = 25 °C	SL03	I _R			130	μΑ
	T _A = 100 °C	SL03	I _R			6.0	mA
	T _A = 25 °C	SL04	I _R			20	μΑ
	T _A = 100 °C	SL04	I _R			6.0	mA

 $^{^{1)}}$ Pulse test: 300 μs pulse width, 1 % duty cycle



Typical Characteristics (Tamb = 25 °C unless otherwise specified)

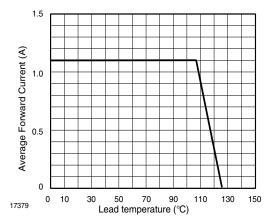


Figure 1. Forward Current Derating Curve

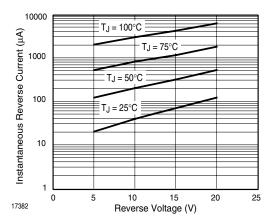


Figure 4. Typical Reverse Current Characteristics - SL02

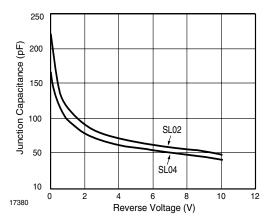


Figure 2. Typical Junction Capacitance

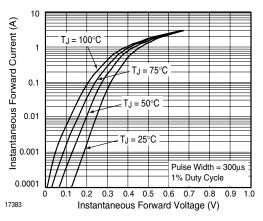


Figure 5. Typical Instantaneous Forward Characteristics - SL03

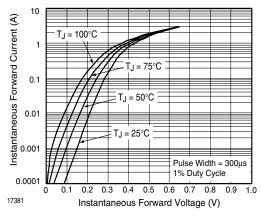


Figure 3. Typical Instantaneous Forward Characterisics - SL02

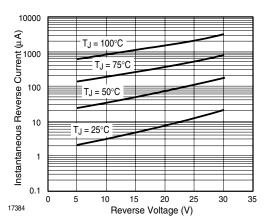
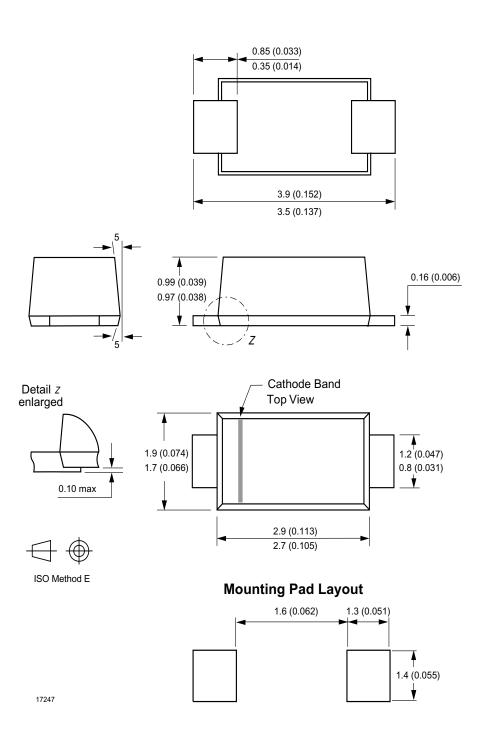


Figure 6. Typical Reverse Current Characteristics - SL03

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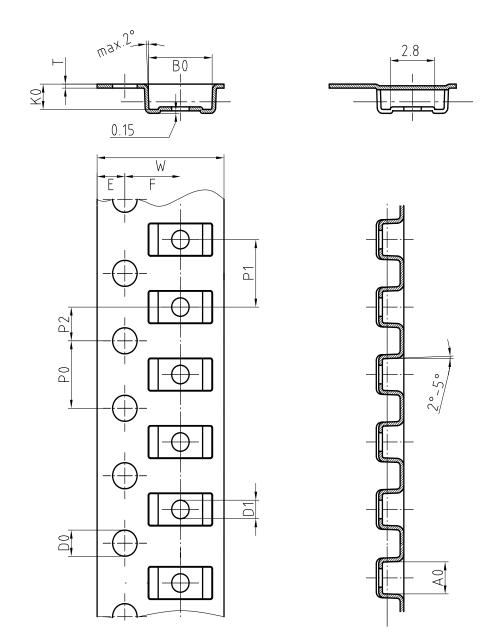
Package Dimensions in mm (Inches)







Blistertape for SMF



Mat:	Α0	В0	K0	W	T	Р0	P2	P1	D0	D1	E	F
PS	1.9	4.0	1.5	8.0	0.235	4.0	2.0	4.0	1.5	1	1.75	3.5

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

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Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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